

IEEE EDS Japan Joint Chapter 会員各位
IEEE EDS Kansai Chapter 会員各位
IEEE SSCS Japan Chapter 会員各位
IEEE SSCS Kansai Chapter 会員各位

IEEE EDS Japan Joint Chapter
Chair 杉井 信之
Vice Chair 田中 徹

4月7日(金) 午後、東京工業大学で GlobalFoundries の Anirban Bandyopadhyay 博士による Distinguished Lecturer の開催を予定しております。奮って御参加下さい。なお、本 Distinguished Lecturer については、当チャプターのホームページ (URL 末尾) に記載予定でありますので、併せてご参照下さい。

「IEEE EDS Distinguished Lecturer 講演会」

主催: IEEE EDS Japan Joint Chapter

共催: IEEE EDS Kansai Chapter, IEEE SSCS Japan Chapter, IEEE SSCS Kansai Chapter

日時: 2023年4月7日金曜日 16:00-17:15 (講演時間 45分の予定)

会場: 東京工業大学大岡山キャンパス 南3号館2階 第1会議室(オンライン接続予定)

参加費: 無料 (下記より事前登録をお願いいたします)

https://docs.google.com/forms/d/e/1FAIpQLSeGN7KMOcZ9tqCpPrrT9UVANOg9MLMy4seteKVEGkOLLIfYDA/viewform?usp=sf_link

講演者:

Anirban Bandyopadhyay, PhD (IEEE Fellow, Senior Director & Head of Strategic Applications, Mobility & Wireless Infrastructure Business Unit, GlobalFoundries Inc.)

講演タイトル:

Silicon Technology Roadmap to address 6G Radio

講演者ご紹介:

Dr. Anirban Bandyopadhyay is the Senior Director and head of Strategic Applications within the Smart Mobile Devices and Wearables business unit of GlobalFoundries, USA. His work is currently focused on hardware architecture and technology evaluations for emerging RF/mmwave and analog/mixed signal-based applications. Prior to joining GlobalFoundries, he was with IBM Microelectronics and with Intel where he worked on different areas like RF Design Enablement, Silicon Photonics, signal integrity in RF and Mixed signal SOC's. Dr. Bandyopadhyay represents GlobalFoundries in different industry consortia and alliances on wireless connectivity applications and is an IEEE Fellow and a Distinguished Lecturer of IEEE Electron Devices Society.

【お問合せ】

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Tokyo/Japan Sections Jt. Chap., ED15: <https://www.ieee-jp.org/section/tokyo/chapter/ED-15/index-e.html>